



100V 175°C NPN LOW SAT MEDIUM POWER TRANSISTOR IN POWERDI5060-8

### Features

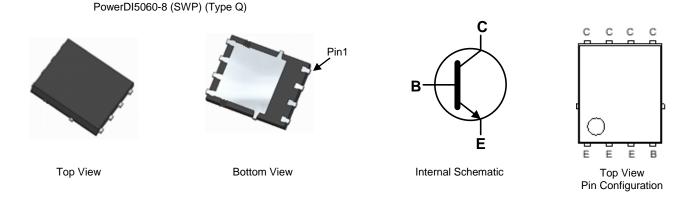
- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 3A Continuous Collector Current
- I<sub>CM</sub> = 6A Peak Pulse Current
- R<sub>CE(SAT)</sub> <150mΩ</li>
- Rated to +175°C—Ideal for High Ambient Temperature Environments
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTN3C100PSQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Finish—Matte Tin Annealed Over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

## Applications

- Power Management
- Load Switch
- Linear Mode Voltage Regulator
- Backlighting Applications



# Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTN3C100PSQ-13	Automotive	DXTN3C100PS	13	12	2500

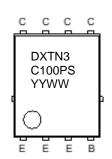
 EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

Notes:



DXTN3 = Product Type Marking Code C100PS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

DXTN3C100PSQ Document number: DS39305 Rev.2 - 2



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Base Current	IB	500	mA
Continuous Collector Current	lc	3	A
Peak Pulse Collector Current	I <sub>CM</sub>	6	A

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation (Note 5)		PD	2.5	W	
Thermal Registeries, Junction to Ambient	(Note 5)	D	60	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>θJA</sub>	140		
Thermal Resistance, Junction to Lead (Note 7)		R <sub>θJL</sub>	5.7	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C		

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

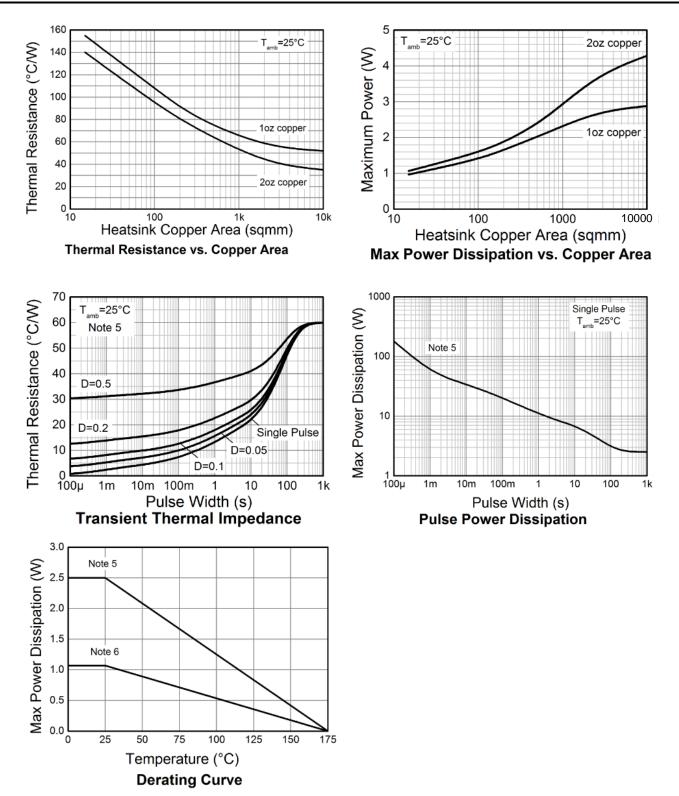
5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is Notes:

measured under still air conditions whilst operating in a steady-state.

Same as note (5), except mounted on minimum recommended pad layout.
Thermal resistance from junction to solder point (at the collector tab).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## Typical Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





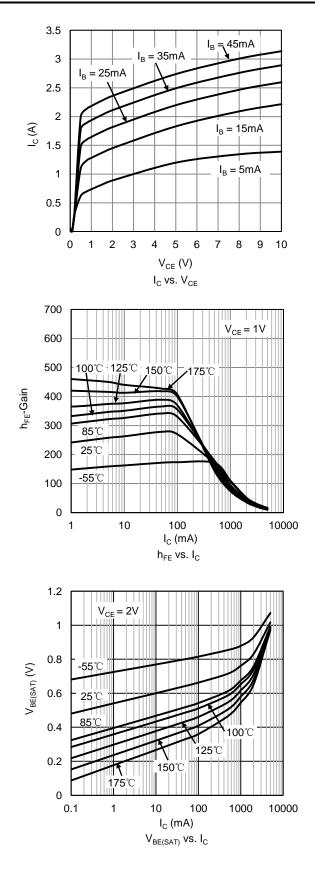
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

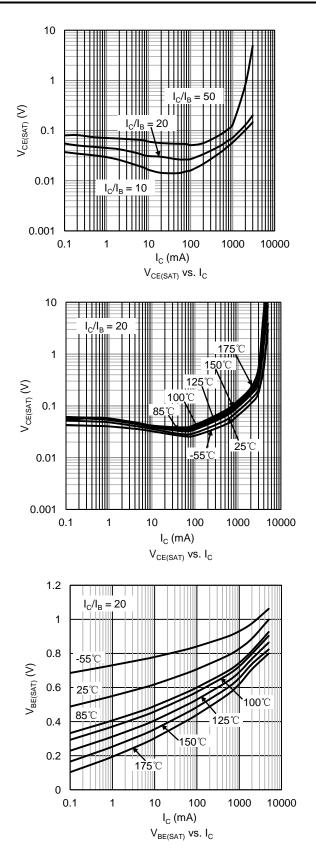
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	—	—	V	$I_{C} = 100 \mu A$	
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	100	_	—	V	$I_{C} = 10 \text{mA}$	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	_	—	V	$I_E = 100 \mu A$	
Collector-Base Cutoff Current		—	_	100	nA	$V_{CB} = 80V$	
Collector-Base Cuton Current	I <sub>CBO</sub>	—	_	50	μA	$V_{CB} = 80V @ T_J = +150^{\circ}C$	
Emitter Cutoff Current	I <sub>EBO</sub>	—	_	100	nA	$V_{EB} = 7V$	
Collector-Emitter Cutoff Current	I <sub>CES</sub>	—	_	100	nA	$V_{CES} = 80V$	
ON CHARACTERISTICS (Note 9)	_				-		
		150	250	—		$I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V}$	
DC Current Gain	hFE	80	250	—		$I_C = 1A, V_{CE} = 10V$	
	TIFE	20	100	—	_	$I_C = 2A, V_{CE} = 10V$	
		10	40	—		$I_C = 3A, V_{CE} = 10V$	
Collector-Emitter Saturation Voltage	V	—	90	150	mV	$I_C = 1A, I_B = 50mA$	
	V <sub>CE(SAT)</sub>	—	225	330	mV	$I_{C} = 3A, I_{B} = 300mA$	
Collector-Emitter Saturation Resistance	R <sub>CE(SAT)</sub>	—	90	150	mΩ	$I_C = 1A, I_B = 50mA$	
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	—	0.86	1.0	V	$I_C = 1A, I_B = 50mA$	
Base-Emilier Saturation Voltage		—	1.0	1.2	v	$I_{C} = 2A, I_{B} = 200mA$	
Base-Emitter Turn-On Voltage	V <sub>BE(ON)</sub>	—	0.67	0.85	V	$I_{C} = 0.1A, V_{CE} = 2V$	
SMALL SIGNAL CHARACTERISTICS							
Current Gain-Bandwidth Product	f⊤		140		MHz	$V_{CE} = 10V, I_C = 100mA, f = 100MHz$	
Output Capacitance	Cobo	_	11		pF	$V_{CB} = 10V$ , f = 1MHz	
Delay Time	t <sub>d</sub>	—	20	—	ns		
Rise Time	tr	—	300	—	ns	]	
Turn-On Time	t <sub>(on)</sub>	—	320	_	ns	$V_{CC} = 12.5V, I_C = 1A$	
Storage Time	ts	—	830	_	ns	$I_{B1} = -I_{B2} = 0.05A$	
Fall Time	t <sub>f</sub>	—	470	—	ns		
Turn-Off Time	t <sub>(off)</sub>	—	1300	_	ns		

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

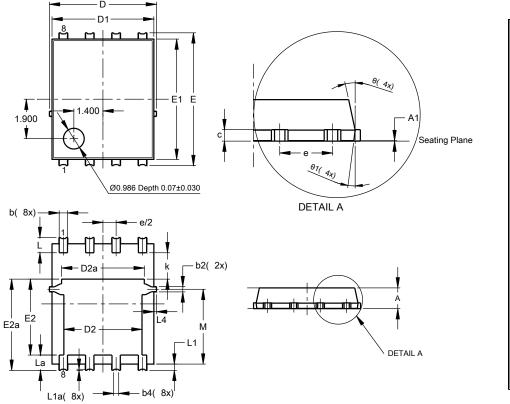






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



#### PowerDI5060-8 (SWP) (Type Q)

Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05	_		
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	C	).25REF			
С	0.230	0.330	0.277		
D		.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	6	.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC	)		
k	1.05	_	—		
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0.050REF				
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	All Dimensions in mm				

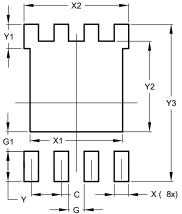
PowerDI5060-8 (SWP)

(Type Q)

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (SWP) (Type Q)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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